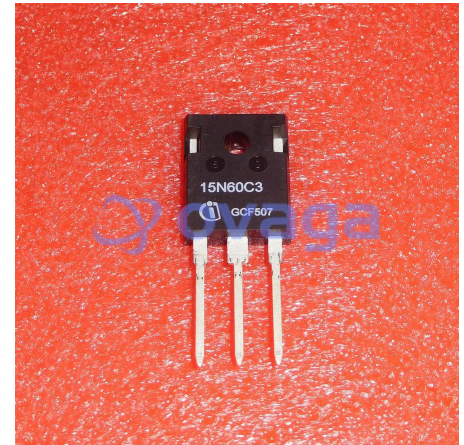


N-Channel MOSFETs >500V...900V; Package: PG-TO247-3; VDS max: 600.0 V;
 Package: TO-247; RDS(on) @ TJ=25°C VGS=10: 280.0 mOhm; IDmax @ TC=25°C:
 15.0 A; IDpuls max: 45.0 A;

Manufacturers	Infineon Technologies Corporation
Package/Case	TO-247
Product Type	Transistors
RoHS	
Lifecycle	



Images are for reference only

Please submit RFQ for SPW15N60C3 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

SPW15N60C3 is a MOSFET transistor from Infineon Technologies.

Features

It has a VDS (Drain-Source Voltage) rating of 600V.

It can handle a continuous drain current of 15A.

It has a low on-resistance of 0.33 ohms.

It is designed to operate at high switching frequencies.

Application

Switching power supplies

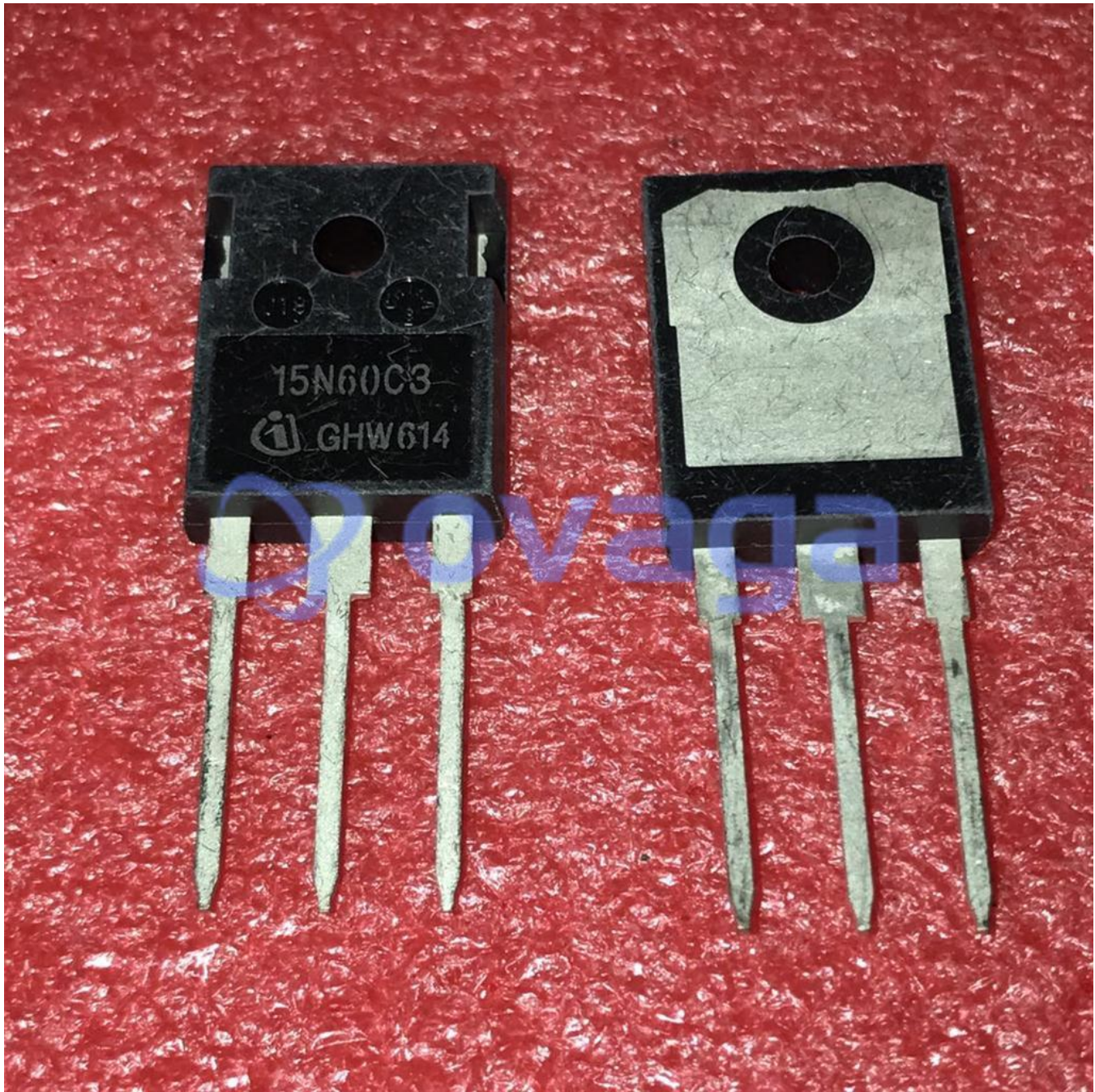
Motor control

Lighting ballasts

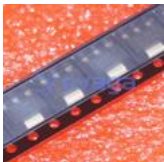
Welding equipment

Inverter circuits





Related Products



[BSP613P](#)

Infineon Technologies Corporation
SOT-223



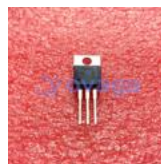
[SPP11N65C3](#)

Infineon Technologies Corporation
TO-220



[SPP07N65C3](#)

Infineon Technologies Corporation
TO-220AB



[SPP07N60S5](#)

Infineon Technologies Corporation
P-TO220-3-1



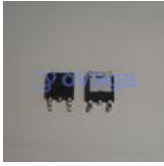
[SPP11N60C3XKSA1](#)

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PG-TO220



[IRF640NSPBF](#)

Infineon Technologies Corporation
PAK-3



[SPD03N60S5](#)

Infineon Technologies Corporation
TO-252



[SPP20N60CFD](#)

Infineon Technologies Corporation
TO-220AB